



DXT651

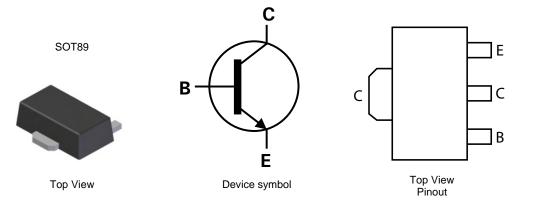
60V LOW V_{CE(sat)} NPN SURFACE MOUNT TRANSISTOR

Features

- **Epitaxial Planar Die Construction** •
- Complementary PNP Type Available (DXT751)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free "Green" Device (Note 2)

Mechanical Data

- Case: SOT89 •
- Case material: molded Plastic. "Green" molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.052 grams (Approximate)



Ordering Information (Note 3)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DXT651-13	KN2	13	12	2,500

Notes: 1. No purposefully added lead.

2. "Green" devices, Halogen and Antimony Free, Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com 3. For Packaging Details, go to our website at http://www.diodes.com.

Marking Information

С		Y	W	w	
KN2					

KN2 = Product Type Marking Code DII = Manufacturer's Marking Code YWW = Date Code Marking Y = Last digit of year (ex: 7 = 2007) WW = Week code (01 - 53)



Maximum Ratings $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	80	V
Collector-Emitter Voltage	V _{CEO}	60	V
Emitter-Base Voltage	V _{EBO}	5	V
Collector Current	Ic	3	A
Peak Pulse Collector Current	I _{CM}	6	A

Thermal Characteristics $@T_A = 25^{\circ}C$ unless otherwise specified

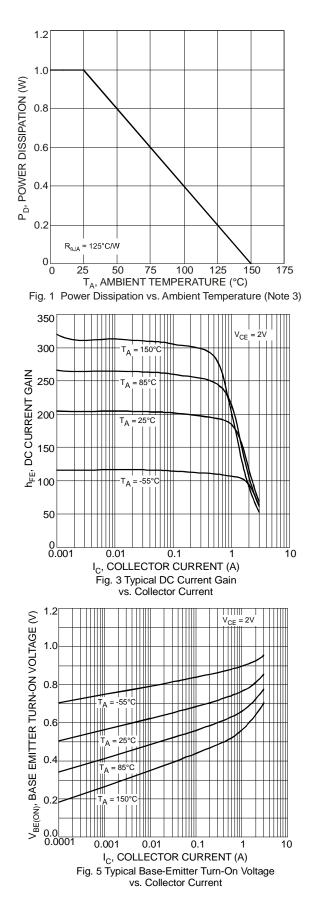
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	PD	1	W
Thermal Resistance, Junction to Ambient Air (Note 4)	R _{0JA}	125	°C/W
Thermal Resistance, Junction to Leads	R _{θJL}	18.2	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

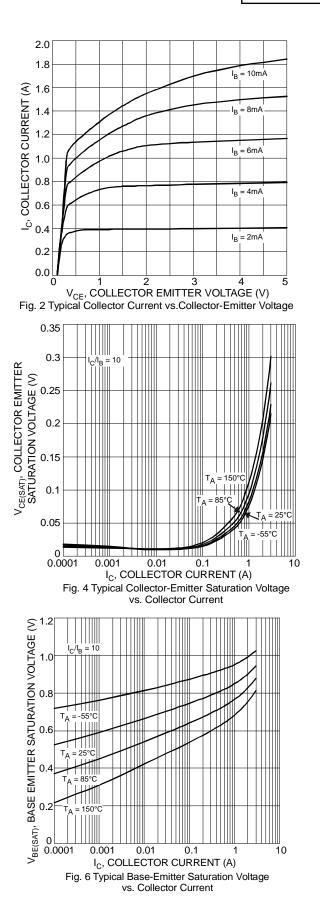
Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
OFF CHARACTERISTICS (Note 5)	-					
Collector-Base Breakdown Voltage	BV _{CBO}	80			V	$I_{\rm C} = 100 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage	BV _{CEO}	60		_	V	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	5	_		V	$I_{\rm E} = 100 \mu A, I_{\rm C} = 0$
Collector-Base Cutoff Current	I _{CBO}	—	—	0.1 10	μA	V _{CB} = 60V, I _E = 0 V _{CB} = 60V, I _E = 0, T _A = 100°C
Emitter-Base Cutoff Current	I _{EBO}	_		0.1	μΑ	$V_{EB} = 4V, I_{C} = 0$
ON CHARACTERISTICS (Note 5)						
Collector-Emitter Saturation Voltage	V _{CE(sat)}	_	0.08 0.23	0.3 0.6	V V	$I_{C} = 1A, I_{B} = 100mA$ $I_{C} = 3A, I_{B} = 300mA$
Base-Emitter Saturation Voltage	V _{BE(sat)}	_	0.85	1.25	V	$I_{\rm C} = 1$ A, $I_{\rm B} = 100$ mA
Base-Emitter Turn-On Voltage	V _{BE(on)}	_	0.8	1	V	$V_{CE} = 2V, I_{C} = 1A$
DC Current Gain	h _{FE}	70 100 80 40	200 200 185 120	 300 	_	$V_{CE} = 2V, I_{C} = 50mA \\ V_{CE} = 2V, I_{C} = 500mA \\ V_{CE} = 2V, I_{C} = 1A \\ V_{CE} = 2V, I_{C} = 2A$
AC CHARACTERISTICS						
Transition Frequency	f _T	140	200		MHz	$V_{CE} = 5V, I_C = 100mA, f = 100MHz$
Output Capacitance	C _{obo}		—	30	pF	V _{CB} = 10V, f = 1MHz
Switching Times	t _{on} t _{off}	_	35 230		ns ns	$V_{CC} = 10V. I_C = 500mA,$ $I_{B1} = I_{B2} = 50mA$

Notes: 4. Device mounted on FR-4 PCB

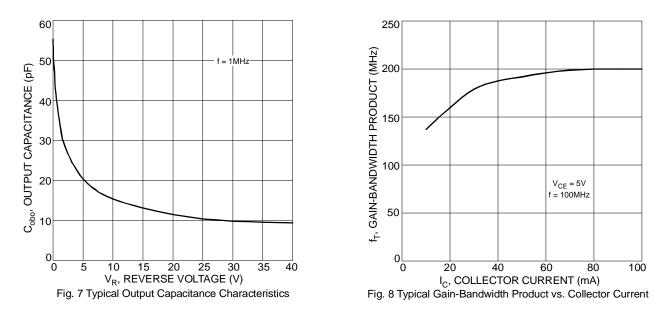
5. Measured under pulsed conditions. Pulse width = 300 s. Duty cycle $\leq 2\%$.



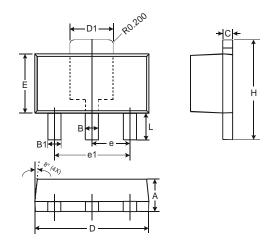






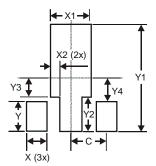


Package Outline Dimensions



SOT89				
Dim	Min	Max		
Α	1.40 1.60			
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.43		
D	4.40	4.60		
D1	1.52	1.83		
Е	2.29	2.60		
е	1.50 Тур			
e1	3.00 Typ			
Н	3.94	4.25		
L	0.89	1.20		
All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500



DXT651

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